

L Number	Hits	Search Text	DB	Time stamp
-	2	("20020042201").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 09:42
-	3156	bpsg and cmp and (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 07:54
-	599	bpsg same cmp same (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 09:45
-	100	bpsg with cmp with (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:08
-	113	(metal or conductive or electrode or tungsten or polysilicon) with bpsg same cmp same (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:09
-	42	(metal or conductive or electrode or tungsten or polysilicon) with bpsg with cmp with (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:19
-	2160	(438/970,959, 692, 693, 760, "698").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 07:54
-	0	("(cmp or polishing) and 7").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:22
-	1787	(cmp or polishing) and ((438/970,959, 692, 693, 760, "698").CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:31
-	288	((cmp or polishing) and ((438/970,959, 692, 693, 760, "698").CCLS.)) and (bpsg and (darc or hard adj oxide or nitride or oxynitride or siN or sion))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:25
-	283	((cmp or polishing) and ((438/970,959, 692, 693, 760, "698").CCLS.)) and (bpsg and (darc or hard adj oxide or nitride or oxynitride or siN or sion)) not ((metal or conductive or electrode or tungsten or polysilicon) with bpsg with cmp with (darc or hard adj oxide or nitride or oxynitride or siN or sion))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:31
-	290	(438/754).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:31
-	290	((438/754).CCLS.) ((cmp or polishing) and ((438/754).CCLS.))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:32

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-	364	((((cmp or polishing) and ((438/970,959,692, 693, 760, "698").CCLS.)) and (bpsg and (darc or hard adj oxide or nitride or oxynitride or siN or sion))) not ((metal or conductive or electrode or tungsten or polysilicon) with bpsg with cmp with (darc or hard adj oxide or nitride or oxynitride or siN or sion))) ((cmp or polishing) and ((438/754).CCLS.))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:32
-	95	(cmp or polishing) and ((438/754).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/28 10:32
-	8923	bpsg and (darc or hard adj oxide or nitride or oxynitride or siN or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 07:54
-	2167	(438/970,959,692,693,760,698).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 07:58
-	2935	(438/970,959,692,693,760,698,745,754).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 08:00
-	1961	((438/970,959,692,693,760,698,745,754).CCLS and (cmp or polishing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 08:00
-	317	((438/970,959,692,693,760,698,745,754).CCLS and (cmp or polishing)) and (bpsg and (darc or hard adj oxide or nitride or oxynitride or siN or sion))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 09:25
-	553	(low adj "k" adj dielectric) same (darc or nitride or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/29 09:28